



#### 80V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> Tc = +25°C	
80V	25mΩ @ V <sub>GS</sub> = 10V	41.7A	
60 V	41mΩ @ V <sub>GS</sub> = 4.5V	32.5A	

#### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

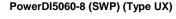
- Synchronous Rectifier
- Backlighting
- Power Management Functions
- DC-DC Converters

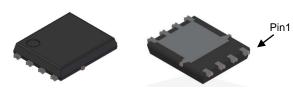
#### **Features**

- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

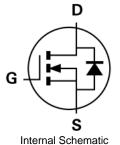
# Mechanical Data

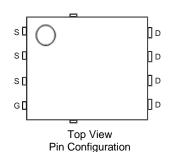
- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)





Top View Bottom View





### **Ordering Information** (Note 4)

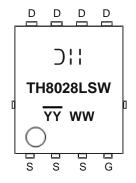
Part Number	Case	Packaging
DMTH8028LPSW-13	PowerDI5060-8 (SWP) (Type UX)	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**

PowerDI5060-8 (SWP) (Type UX)



DIII = Manufacturer's Marking
TH8028LSW = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 20 = 2020)
WW = Week Code (01 to 53)



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	80	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	ID	41.7 29.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	166.8	А
Maximum Continuous Body Diode Forward Current (Note 6)		Is	41	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Ism	166.8	А
Avalanche Current, L = 0.3mH (Note 9)		las	12.5	А
Avalanche Energy, L = 0.3mH (Note 9)		E <sub>AS</sub>	23.4	mJ

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	3.9	W
Thermal Resistance, Junction to Ambient (Note 5)	RθJA	38	°C/W	
Total Power Dissipation (Note 6)	T <sub>C</sub> = +25°C	P <sub>D</sub>	65	W
Thermal Resistance, Junction to Case (Note 6)		R <sub>θ</sub> JC	2.3	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

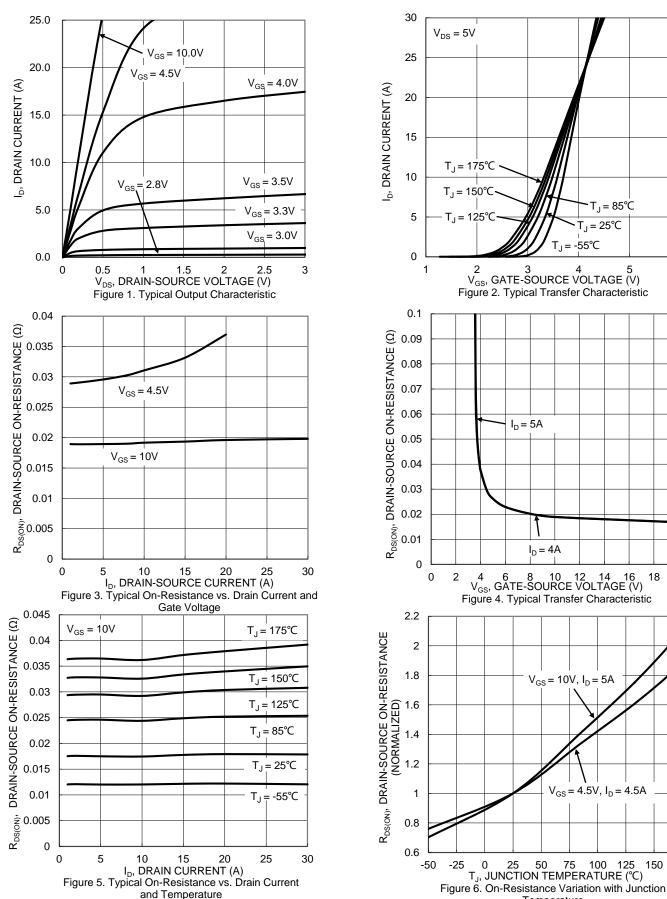
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

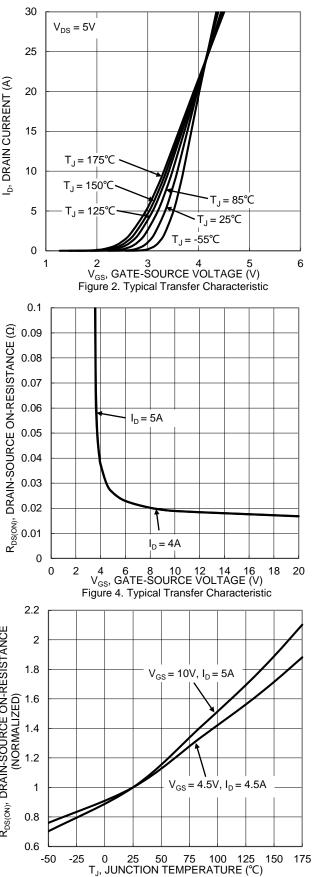
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	80	_	_	V	$V_{GS} = 0V$ , $I_{D} = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	1	μΑ	$V_{DS} = 64V$ , $V_{GS} = 0V$	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.3	_	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Dagger	l	18	25	0	V <sub>GS</sub> = 10V, I <sub>D</sub> = 5A	
Static Dialii-Source Oil-Resistance	RDS(ON)	l	28	41	mΩ	$V_{GS} = 4.5V, I_D = 4.5A$	
Diode Forward Voltage	VsD	l	0.8	1.2	V	$V_{GS} = 0V$ , $I_{S} = 5A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>		641			V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	272	_	pF		
Reverse Transfer Capacitance	Crss		32				
Gate Resistance	Rg	1	1.4		Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$	
Total Gate Charge (VGS = 4.5V)	Qg	1	5.4				
Total Gate Charge (VGS = 10V)	Qg	l	10.4		nC	V <sub>DS</sub> = 40V, I <sub>D</sub> = 7.5A	
Gate-Source Charge	Qgs	l	1.8		IIC		
Gate-Drain Charge	$Q_{gd}$	l	2.4				
Turn-On Delay Time	td(ON)	_	11.3	_		$V_{DD} = 40V, V_{GS} = 4.5V,$ $R_G = 2.7\Omega, I_D = 10A$	
Turn-On Rise Time	t <sub>R</sub>	_	14.3	_	no		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	10.8		ns		
Turn-Off Fall Time	tF		8.3				
Body Diode Reverse Recovery Time	trr	1	25.5	1	ns	I= -7.54 di/dt - 1004/up	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	20.6	_	nC	I <sub>F</sub> = 7.5A, di/dt = 100A/μs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

- 6. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.
- 9.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25$ °C.

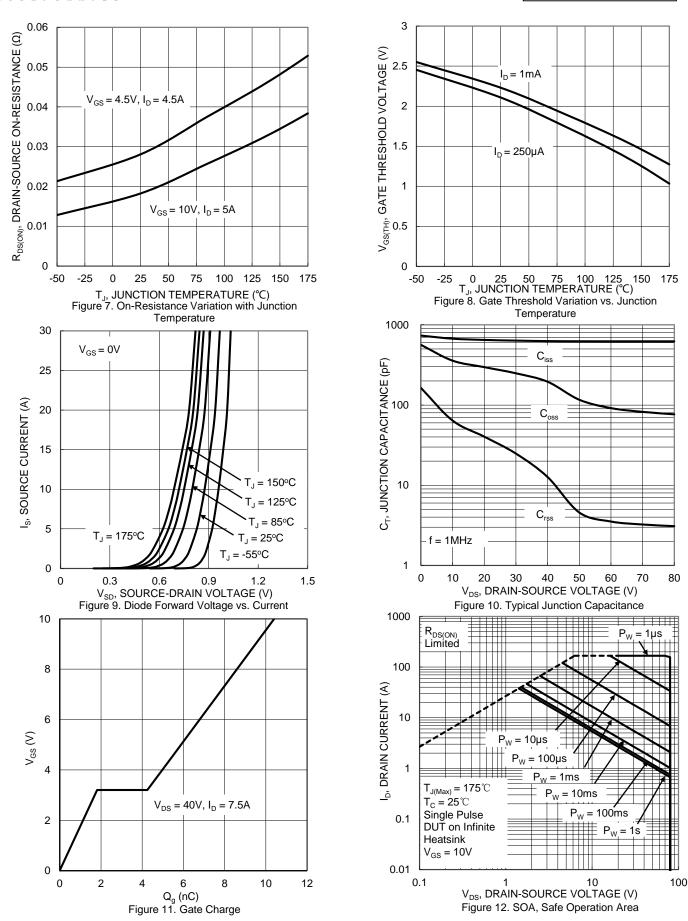






Temperature







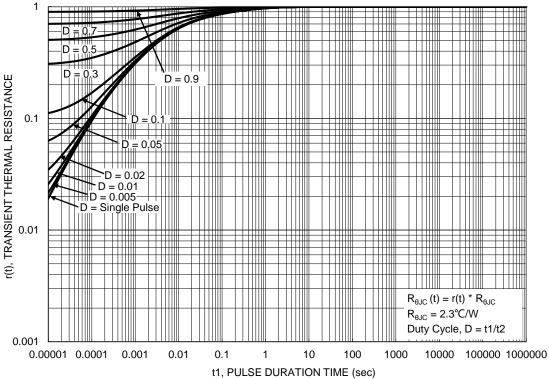


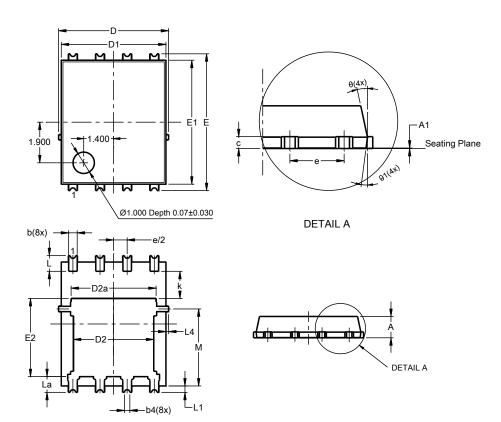
Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (SWP) (Type UX)

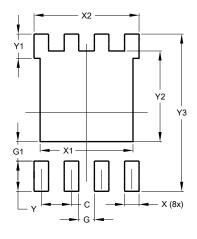


PowerDI5060-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4		).25REF			
С	0.230	0.330	0.277		
D	5	.15 BS0			
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
E	6	.40 BS0			
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е		.27BSC	;		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0.050REF				
L4	0.025	0.225	0.125		
M	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value		
Dimensions	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	4.420		
Υ	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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